

TSS40L

0.2Amp Surface Mount Schottky Barrier Diode

1005

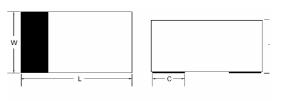


Features

- ∻ Designed for mounting on small surface
- ∻ Extremely thin/leadless package
- ∻ Low capacitance
- ∻ Low forward voltage drop
- أ High temperature soldering: 260°C/10 seconds at terminals
- ∻ Chip version in 1005

Mechanical Data

- Case: 1005 Standard package, molded plastic Terminals: Gold plated, solderable per ∻ ∻
 - MIL-STD-750, method 2026.
- ∻ Polarity: Indicated by cathode band
- ∻ Mounting position: Any
- ∻ Package code: RW
- ∻ Weight: 0.006 gram (approximately)





ITEM	1005		
L	0.102(2.60)		
	0.095(2.40)		
W	0.051(1.30)		
	0.043(1.10)		
Т	0.035(0.90)		
	0.027(0.70)		
С	0.020(0.50)		
	Typical		
D	0.040(1.00)		
	Typical		

Maximum Ratings T _A =25 °C unless otherwise specified				
Type Number	Symbol	1005	Units	
Repetitive Peak Reverse Voltage	V _{RRM}	40	V	
Reverse Voltage	V _R	40	V	
RMS Reverse Voltage	V _{R(RMS)}	28	V	
Average Forward Current	I _O	200	mA	
Peak Forward Surge Current 8.3ms single half sine-wave superimposed on rate load (JEDEC method)	I _{FSM}	600	mA	
Power Dissipation	Pd	200	mW	
Forward Voltage IF=1.0mA IF=40mA	V _F	0.38 1.0	V	
Reverse Leakage Current VR=30V	I _R	0.2	uA	
Typical capacitance between terminals VR=0V, f =1.0MHz reverse voltage	CJ	3	pF	
Reverse Recovery Time (IF=IR=10mA, Irr=0.1x IR, RL=100Ω)	Trr	5	nS	
Junction Temperature	ΤJ	-65 to + 125	°C	
Storage Temperature	T _{STG}	-65 to + 125	°C	

Dimensions in inches and (millimeters)



RATINGS AND CHARACTERISTIC CURVES(TSS40L)

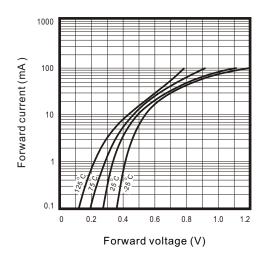
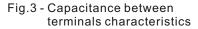
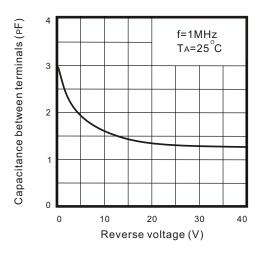


Fig. 1 - Forward characteristics





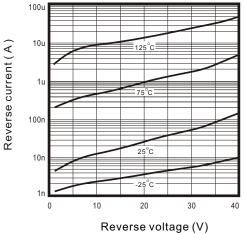


Fig. 2 - Reverse characteristics

Fig.4 - Current derating curve

